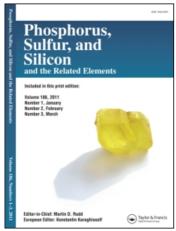
This article was downloaded by:

On: 28 January 2011

Access details: Access Details: Free Access

Publisher Taylor & Francis

Informa Ltd Registered in England and Wales Registered Number: 1072954 Registered office: Mortimer House, 37-41 Mortimer Street, London W1T 3JH, UK



Phosphorus, Sulfur, and Silicon and the Related Elements

Publication details, including instructions for authors and subscription information: http://www.informaworld.com/smpp/title~content=t713618290

Editorial board page for "Phosphorus, Sulfur, and Silicon and the Related Elements", Volume 139, Number 1

To cite this Article (1998) 'Editorial board page for "Phosphorus, Sulfur, and Silicon and the Related Elements", Volume 139, Number 1', Phosphorus, Sulfur, and Silicon and the Related Elements, 139: 1, a

To link to this Article: DOI: 10.1080/10426509808035672 URL: http://dx.doi.org/10.1080/10426509808035672

PLEASE SCROLL DOWN FOR ARTICLE

Full terms and conditions of use: http://www.informaworld.com/terms-and-conditions-of-access.pdf

This article may be used for research, teaching and private study purposes. Any substantial or systematic reproduction, re-distribution, re-selling, loan or sub-licensing, systematic supply or distribution in any form to anyone is expressly forbidden.

The publisher does not give any warranty express or implied or make any representation that the contents will be complete or accurate or up to date. The accuracy of any instructions, formulae and drug doses should be independently verified with primary sources. The publisher shall not be liable for any loss, actions, claims, proceedings, demand or costs or damages whatsoever or howsoever caused arising directly or indirectly in connection with or arising out of the use of this material.

Phosphorus, Sulfur, and Silicon and the Related Elements

Editor in Chief: R. R. Holmes

Department of Chemistry, University of Massachusetts, Amherst, Massachusetts 01003 U.S.A.

European Editor: L. Maier

Novartis International INC, R-1098.P.10, CIBA-GEIGV AG, CH-4002 Basel, Switzerland

Associate Editors

Editor Emeritus

W. Walter

University of Hamburg Institut für Organische Chemi Martin-Luther-King-Platz 6 D-20146 Hamburg, Germany

J. G. Verkade

Department of Chemistry Iowa State University Ames, Iowa 50010, USA

L. Horner

Mainz, Germany

R. West

(For Communications and Reviews)

Editorial Board

A. I. Konovalor

R. P. Arshinova Monsanto St. Louis, Missouri W. Bentrude University of Utah Salt Lake City K. D. Berlin Oklahoma State University, Stillwater E. Block State University of New York at Albany H. Bock The University Frankfurt, Germany R. Burgada Université P. et M. Curie Paris, France R. Contreras Centro de Investigacion de Estudios Avanzados del IPN, Mexico J. Y. Corev University of Missouri. R. Corriu University of Science and Technology of Languedoc, France S. Cremer Marquette University Milwaukee, Wisconsin F. A. Davis Temple University Philadelphia Pennsylvania

S. A. Evans, Jr. University of North Carolina at Chapel Hill L. Field Vanderbilt University Nashville, Tennessee E. Fluck Gmelin Institute Frankfurt, Germany P. Gaspar Washington University St. Louis, Missouri C. D. Hall King's College London, UK S. Husebye Norway N. Inamoto University of Tokyo Japan K. Jurkschat Universitat J. F. King

University of Bergen Dortmund, Germany University of Western Ontario O. I. Kolodiazhnyi National Academy of Sciences of Ukraine Kiev, Ukraine

Arbuzov Institute of Organic and Physical Chemistry, Russia S. S. Krishnamurthy Indian Institute of Science, Bangalore, India J. P. Majoral Universite Paul Sabatier Toulouse, France S. Masson Université de Caen France T. A. Mastryukova Russian Academy of Sciences Moscow: Russia F. Mathey Ecole Polytechnique Palaiseau, France M. Mikolajczyk Polish Academy of Sciences Lodz, Poland G. Modena The University Padua, Italy J. F. Nixon University of Sussex Brighton, UK E. E. Nifant'ev V.I. Lenin State Pedag, Inst.

Chemistry Osaka, Japan L. D. Quin University of Massachusetts Amherst H. Roesky The University Gottingen, Germany H. Sakurai Science University of Tokyo Chiba, Japan H. Schmidbaur Technical University Munich, Germany A. Schmidpeter The University Munich, Germany R. Schmutzler The University Braunschweig. Germany R. Steudel Technical University of Berlin, Germany B. S. Thyagarajan The University of Texas at San Antonio J. C. Van de Grampel University of Groningen The Netherlands

M. Veith Universität des

Saarlandes, Germany

S. Oae

Institute of Heteroatom

University of Wisconsin, Madison P. Wisian-Neilson Southern Methodist University Dallas, Texas B. Władislaw University of São Paulo, Brazil R. Wolf Université Paul Sabatier Toulouse, France C. Yuan Shanghai Institute of Organic Chemistry PRC H. Zimmer University of Cincinnati, Ohio R. A. Zingaro Texas A&M University College Station B. Zwanenburg University of Nijmegen The Netherlands

Aims and Scope

Phosphorus, Sulfur, and Silicon and the Related Elements welcomes submissions involving the organic, inorganic, and biochemistry of phosphorus (including arsenic, antimony, and bismuth), sulfur (including selenium and tellurium), and silicon (including germanium and tin). In addition to research describing new chemistry of a particular element, especially welcome are presentations emphasizing relationships between elements and families of elements: for example, research comparing synthetic, mechanistic, or structural features providing new insight leading to a more rapid advance of science in these areas.

Moscow, Russia

Original articles, communications, and selected reviews of broad interest will be considered for publication. Manuscripts may include illustrative material in color if this will enhance the presentation. There are no page charges and 25 free reprints will be supplied to the principal author. Regular papers may be sent to R. R. Holmes in Amherst or to L. Maier in Basel. Communications and reviews should be sent to W. Walter in Hamburg or J. G. Verkade in Ames.

Notes for contributors, including information on communications and reviews, can be found at the back of the journal

General Information

Please see the inside back cover for information on subsciption rates, photocopy license, and article reprints.

© 1998 OPA (Overseas Publishers Association) N.V. Published by license under the Gordon and Breach Science Publishers imprint. All rights reserved.

Except as permitted under national laws or under the photocopy license described below, no part of this publication may be reproduced or transmitted in any form or by any means, electronic, mechanical, photocopying or otherwise, or stored in a retrieval system of any nature, without the advance written permission of the Publisher.

A CD-ROM ARCHIVE version (which may include visual data such as 3-D animations and video clips) is available for this journal at a nominal extra charge to

Additional information is also available through the Publisher's web home page site at http://www.gbhap.com. Full text on-line access and electronic author submissions may also be availab

Editorial enquiries by e-mail: <editlink@gbhap.com>